

STPOWER 1350 V IH2 SERIES IGBTs



Higher voltage range for induction cookers



Maximize efficiency in single-switch quasi-resonant converters for induction heating systems

Specifically designed for induction heating applications, the 1350 V IH2 series in trench gate field-stop IGBT technology offers higher breakdown voltage, lower V_{CEsat} and lower thermal resistance.

Moreover, thanks to the low drop diode and optimized turn-off energy, this series is ideal for maximizing efficiency in single-switch quasi-resonant converters over a wide switching frequency range from 16 to 60 kHz.

Finally, the higher breakdown voltage enhances reliability and robustness, providing suitable margin under all operating conditions.

KEY FEATURES & BENEFITS

- 1350 V trench gate field-stop IGBT
- Current capability: 25-35 A
- Low conduction losses
- Optimized turn-off energy for soft-switching commutation
- Low drop copacked diode
- Higher reliability and robustness thanks to:
 - Higher breakdown voltage
 - Maximum junction temperature T_J of 175 °C
- Available in TO-247 Long leads

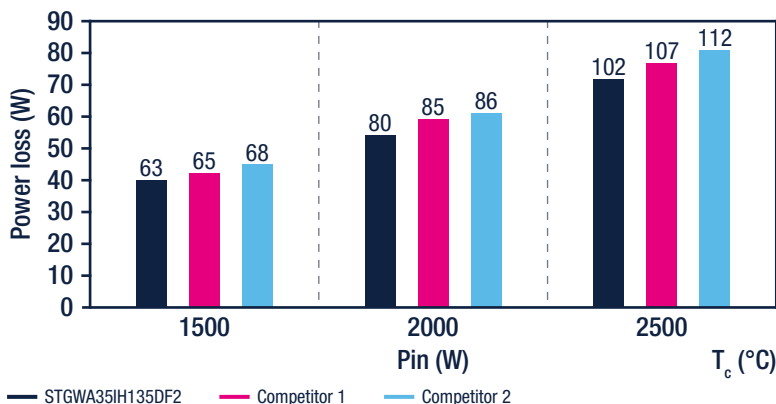
KEY APPLICATIONS

- Induction cookers
- Inverterized microwave ovens
- Rice cookers

Application benchmark

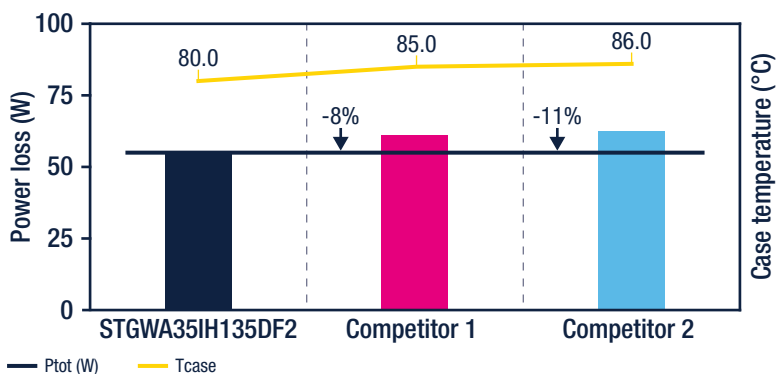
Figure 1 shows a comparison between STGWA35IH135DF2 and competitor products. The test was performed in a single-switch quasi-resonant converter (a typical induction cooker topology) from 1.5 to 2.5 kW power at 25 °C ambient temperature. The columns show the total power loss, while the values on top shows the measured case temperature.

Figure 1: Power loss and T_c vs input power



The STGWA35IH135DF2 clearly demonstrates better performance than the main competitors in terms of power losses and case temperature over the entire input power range, with 8-11% less power loss at 2 kW input power, as shown in figure below:

Figure 2: Power loss and T_c in 2 kW P_{in}



The new ST 1350V IH2 series IGBT therefore represents the best solution for single-switch quasi-resonant converters.

Product portfolio

Part Number	BV_{CES} (V)	I_{CN} (A)	V_{Cesat}^1 (V)	E_{OFF}^2 (mJ)	V_F (V) ¹	Package
STGWA25IH135DF2	1350	25	1.7	0.39	1.15	T0-247 Long leads
STGWA25IH135DF2		35	1.7	0.58	1.2	

Note: 1. @ $V_{GE} = 15$ V, I_{CN} , $T_J = 25$ °C
 2. Switching characteristics on capacitive load



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